

## 30V N-Channel Power MOSFET

30V, 50A, 9mΩ

### FEATURES

- Fast switching
- Halogen Free
- G-S ESD Protection Diode Embedded

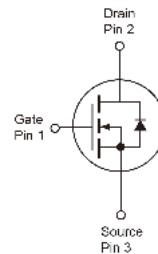
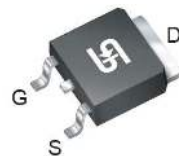
### APPLICATION

- MB / VGA / Vcore
- POL Applications
- SMPS 2<sup>nd</sup> SR

KEY PERFORMANCE PARAMETERS		
PARAMETER	VALUE	UNIT
$V_{DS}$	30	V
$R_{DS(on)}$ (max)	$V_{GS} = 10V$	9
	$V_{GS} = 4.5V$	14
$Q_g$	7.5	nC



TO-252 (DPAK)



**Notes:** Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-Source Voltage	$V_{DS}$	30	V
Gate-Source Voltage	$V_{GS}$	$\pm 20$	V
Continuous Drain Current	$I_D$	$T_C = 25^\circ\text{C}$	50
		$T_C = 100^\circ\text{C}$	32
Pulsed Drain Current (Note 1)	$I_{DM}$	200	A
Total Power Dissipation	$P_D$	$T_C = 25^\circ\text{C}$	40
		Derate above $T_C = 25^\circ\text{C}$	0.32
Single Pulsed Avalanche Energy (Note 2)	$E_{AS}$	45	mJ
Single Pulsed Avalanche Current (Note 2)	$I_{AS}$	30	A
Operating Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature Range	$T_{STG}$	- 55 to +150	$^\circ\text{C}$

<b>THERMAL PERFORMANCE</b>			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction to Case Thermal Resistance	$R_{\theta JC}$	3.1	$^{\circ}C/W$
Junction to Ambient Thermal Resistance	$R_{\theta JA}$	62	$^{\circ}C/W$

**Notes:**  $R_{\theta JA}$  is the sum of the junction-to-case and case-to-ambient thermal resistances. The case thermal reference is defined at the solder mounting surface of the drain pins.  $R_{\theta JA}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.  $R_{\theta JA}$  shown below for single device operation on FR-4 PCB in still air.

<b>ELECTRICAL SPECIFICATIONS</b> ( $T_J = 25^{\circ}C$ unless otherwise noted)						
PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
<b>Static</b> (Note3)						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 250\mu A$	$BV_{DSS}$	30	--	--	V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu A$	$V_{GS(TH)}$	1.2	1.6	2.5	V
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	$I_{GSS}$	--	--	$\pm 10$	$\mu A$
Zero Gate Voltage Drain Current	$V_{DS} = 30V, V_{GS} = 0V$	$I_{DSS}$	--	--	1	$\mu A$
	$V_{DS} = 24V, T_J = 125^{\circ}C$		--	--	10	
Forward Transconductance	$V_{DS} = 10V, I_D = 8A$	$g_{fs}$	--	9.5	--	S
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 16A$	$R_{DS(ON)}$	--	7.5	9	m $\Omega$
	$V_{GS} = 4.5V, I_D = 8A$		--	9.6	14	
<b>Dynamic</b> (Note4)						
Total Gate Charge	$V_{DS} = 15V, I_D = 20A,$ $V_{GS} = 4.5V$	$Q_g$	--	7.7	--	nC
Gate-Source Charge		$Q_{gs}$	--	1.9	--	
Gate-Drain Charge		$Q_{gd}$	--	2.8	--	
Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ $f = 1MHz$	$C_{iss}$	--	680	--	pF
Output Capacitance		$C_{oss}$	--	150	--	
Reverse Transfer Capacitance		$C_{rss}$	--	70	--	
Gate Resistance	$V_{GS}=0V, V_{DS}=0V,$ $f=1MHz$	$R_g$	--	2.7	--	$\Omega$
<b>Switching</b> (Note5)						
Turn-On Delay Time	$V_{DD}=15V, V_{GS}=10V,$ $R_G=3.3\Omega, I_D=-15A$	$t_{d(on)}$	--	4.8	--	ns
Turn-On Rise Time		$t_r$	--	12.5	--	
Turn-Off Delay Time		$t_{d(off)}$	--	27.6	--	
Turn-Off Fall Time		$t_f$	--	8.2	--	
<b>Source-Drain Diode</b> (Note3)						
Forward Voltage	$V_{GS} = 0V, I_S = 1A$	$V_{SD}$	--	--	1	V
Continuous Drain-Source Diode	$V_G=V_D=0V$	$I_S$	--	--	50	A
Pulse Drain-Source Diode	Force Current	$I_{SM}$	--	--	200	A

**Notes:**

1. Repetitive Rating : Pulsed width limited by maximum junction temperature.
2.  $V_{DD}=25V, V_{GS}=10V, L=0.1mH, I_{AS}=30A, R_G=25\Omega,$  Starting  $T_J=25^{\circ}C$ .
3. Pulse test:  $PW \leq 300\mu s,$  duty cycle  $\leq 2\%$
4. For DESIGN AID ONLY, not subject to production testing.
5. Switching time is essentially independent of operating temperature

**ORDERING INFORMATION**

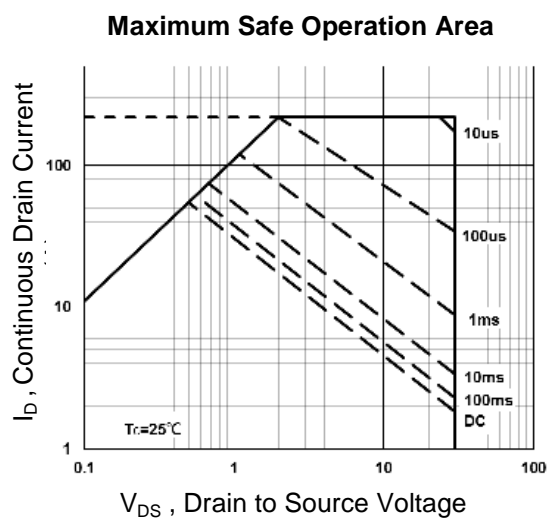
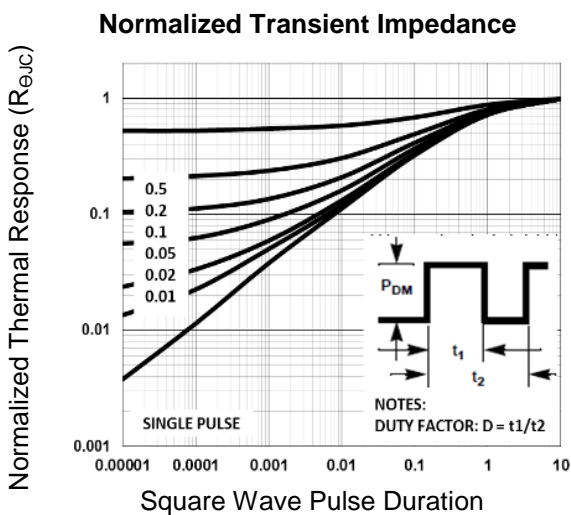
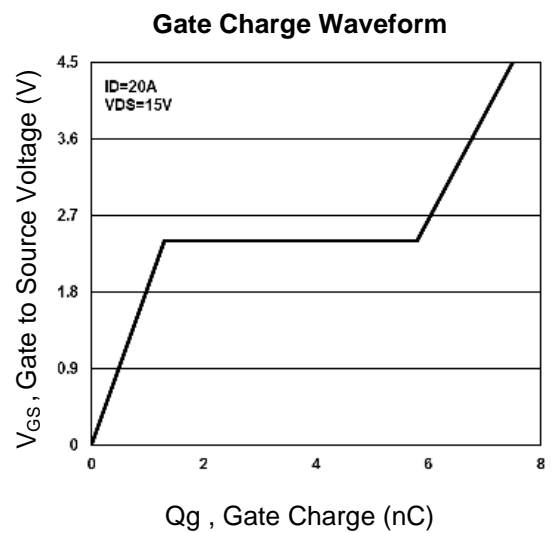
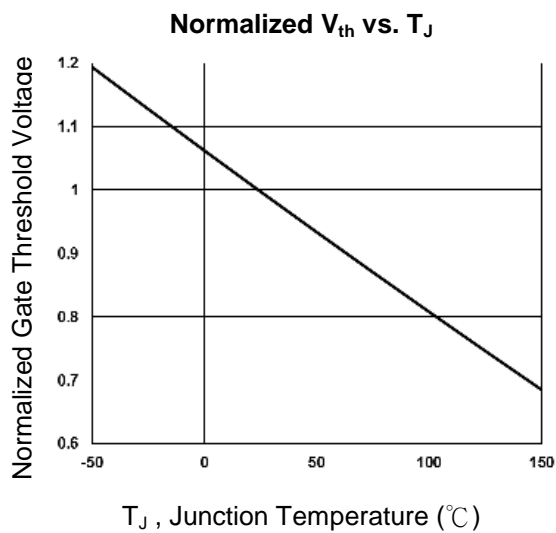
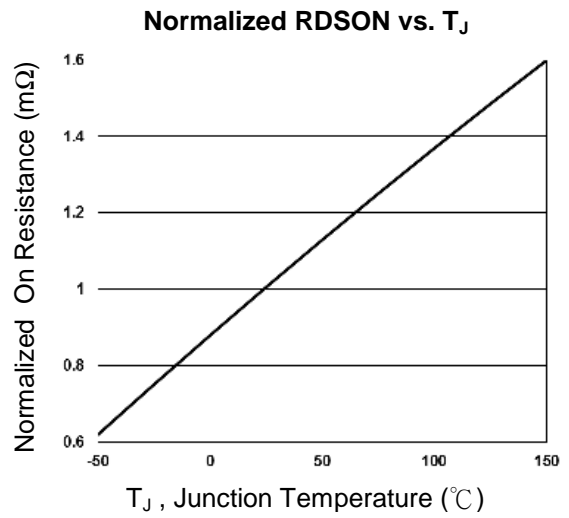
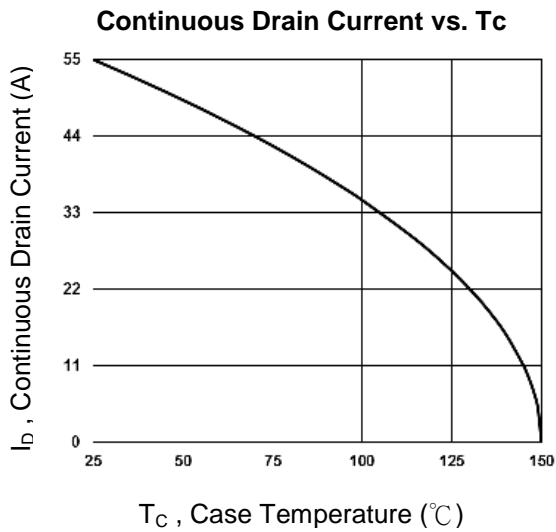
<b>PART NO.</b>	<b>PACKAGE</b>	<b>PACKING</b>
TSM090N03ECP ROG	TO-252	2,500pcs / 13" Reel

**Note:**

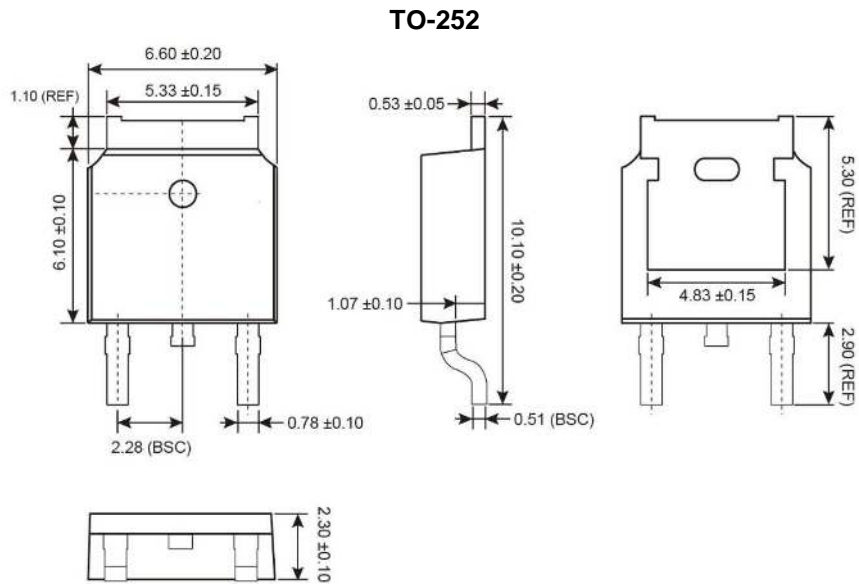
1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
2. Halogen-free according to IEC 61249-2-21 definition

**CHARACTERISTICS CURVES**

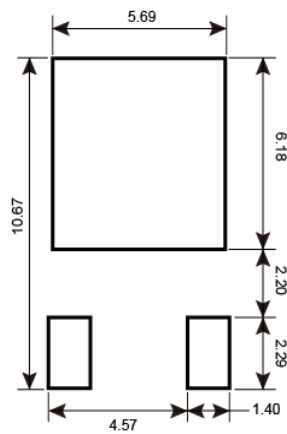
( $T_C = 25^\circ\text{C}$  unless otherwise noted)



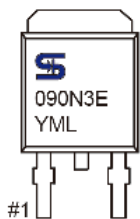
**PACKAGE OUTLINE DIMENSIONS** (Unit: Millimeters)



**SUGGESTED PAD LAYOUT** (Unit: Millimeters)



**MARKING DIAGRAM**



- Y** = Year Code
- M** = Month Code for Halogen Free Product
- O** =Jan    **P** =Feb    **Q** =Mar    **R** =Apr
- S** =May    **T** =Jun    **U** =Jul    **V** =Aug
- W** =Sep    **X** =Oct    **Y** =Nov    **Z** =Dec
- L** = Lot Code

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